8-bit Shift Register

HITACHI

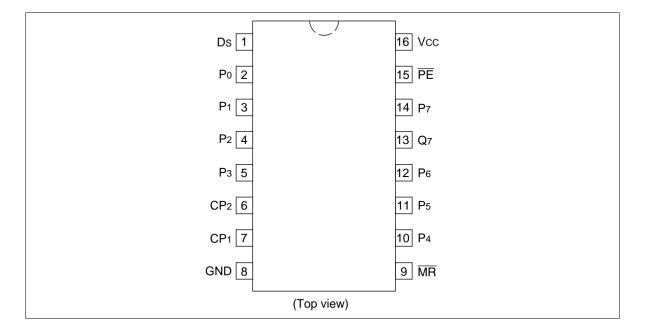
Description

The HD74AC166/HD74ACT166 is an 8-bit, serial or parallel-in, serial-out shift register using edge triggered D-type flip-flops. Serial and parallel entry are synchronous, with state changes initiated by the rising edge of the clock. An asynchronous Master Reset overrides other inputs and clears all flip-flops. The circuit can be clocked from two sources or one CP input can be used to trigger the other.

Features

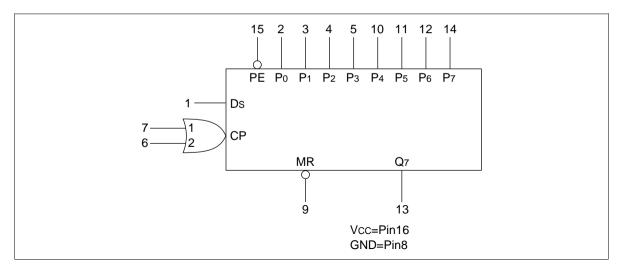
- Outputs Source/Sink 24 mA
- HD74ACT166 has TTL-Compatible Inputs

Pin Arrangement





Logic Symbol



Pin Names

CP₁, CP₂ Clock Pulse Inputs (Active Rising Edge)

D_s Serial Data Input

PE Parallel Enable Input (Active Low)

P₀ to P₇ Parallel Data Inputs

MR Asynchronous Master Reset Input (Active Low)

Q₇ Last Stage Output

Functional Description

Operation is synchronous (except for Master Reset) and state changes are initiated by the rising edge of either clock input if the other clock input is Low. When one of the clock inputs is used as an active High clock inhibt, it should attain the High state while the other clock is still in the High state following the previous operation. When the Parallel Enable (\overline{PE}) input is Low, data is loaded into the register from the Parallel Data (P_0 to P_7) inputs on the next rising edge of the clock. When \overline{PE} is High, information is shifted from the Serial Data (D_s) input to Q_0 and all data in the register is shifted one bit position (i.e., $Q_0 \rightarrow Q_1$, $Q_1 \rightarrow Q_2$, etc.) on the rising edge of the clock.

Truth Table

Inputs

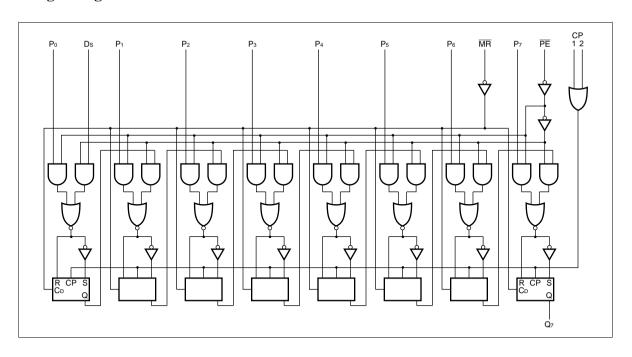
					Parallel	Interna	Outputs	Output
MR	PE	CP ₂	CP ₁	\mathbf{D}_{s}	P ₀ to P ₇	Q _o	$Q_{_{6}}$	Q ₇
L	Х	Х	Х	Х	Х	L	L	L
Н	Х	L	L	Х	Х	Q_{A0}	Q_{B0}	Q _{H0}
Н	L	L		Х	a h	а	b	h
Н	Н	L		Н	Х	Н	Q_{An}	Q_{Gn}
Н	Н	L		L	Х	L	Q_{An}	Q_{Gn}
Н	Х	Н	\int	Х	Х	Q_{A0}	Q_{B0}	Q_{H0}

H : High Voltage Level
L : Low Voltage Level

X : Immaterial

√: Low-to-High Clock Transition

Logic Diagram



DC Characteristics (unless otherwise specified)

Item	Symbol	Max	Unit	Condition
Maximum quiescent supply current	I _{cc}	80	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$, Ta = Worst case
Maximum quiescent supply current	I_{cc}	8.0	μΑ	$V_{IN} = V_{CC}$ or ground, $V_{CC} = 5.5 \text{ V}$, $Ta = 25^{\circ}\text{C}$
Maximum additional I _{cc} /input (HD74ACT166)	I _{CCT}	1.5	mA	$V_{IN} = V_{CC} - 2.1 \text{ V}, V_{CC} = 5.5 \text{ V},$ Ta = Worst case

AC Characteristics: HD74AC166

			Ta = + C _L = 5			Ta = -4 C _∟ = 50	0°C to +85°C pF	
Item	Symbol	V _{cc} (V)*1	Min	Тур	Max	Min	Max	Unit
Maximum clock	f _{max}	3.3	75	_	_	65	_	MHz
frequency		5.0	100	_	_	80	_	_
Propagation delay	t _{PLH}	3.3	1.0	11.0	14.5	1.0	15.5	ns
CP ₁ or CP ₂ to Q ₇		5.0	1.0	9.5	11.5	1.0	12.5	_
Propagation delay	t _{PHL}	3.3	1.0	10.5	14.0	1.0	15.0	_
CP ₁ or CP ₂ to Q ₇		5.0	1.0	9.0	11.0	1.0	12.0	_
Propagation delay	t _{PHL}	3.3	1.0	9.5	12.0	1.0	13.0	_
\overline{MR} to $Q_{\scriptscriptstyle{7}}$		5.0	1.0	6.5	9.0	1.0	10.0	_

Note: 1. Voltage Range 3.3 is $3.3 \text{ V} \pm 0.3 \text{ V}$ Voltage Range 5.0 is $5.0 \text{ V} \pm 0.5 \text{ V}$

AC Operating Requirements: HD74AC166

			Ta = +25°C C _L = 50 pF		$Ta = -40^{\circ}C$ to +85°C $C_{L} = 50 \text{ pF}$	
Item	Symbol	V _{cc} (V)*1	Тур	Guaranteed	Minimum	Unit
Setup time	t _{su}	3.3	3.0	5.5	6.0	ns
$\overline{\text{PE}}$ or P_n or D_s to CP_n		5.0	2.0	4.0	4.5	
Hold time	t _h	3.3	-1.5	3.0	3.0	_
CP_{\scriptscriptstylen} to \overline{PE} or P_{\scriptscriptstylen} or D_{\scriptscriptstyleS}		5.0	-0.5	3.0	3.0	_
Pulse width	t _w	3.3	2.0	5.5	7.0	_
CP_n or \overline{MR}		5.0	2.0	4.5	5.0	_
Recovery time	t _{rec}	3.3	-2.5	0.0	0.0	_
MR to CP _n		5.0	-1.5	0.0	0.0	_

Note: 1. Voltage Range 3.3 is $3.3 \text{ V} \pm 0.3 \text{ V}$ Voltage Range 5.0 is $5.0 \text{ V} \pm 0.5 \text{ V}$

AC Characteristics: HD74ACT166

	Ta = +25°C C _L = 50 pF			Ta = -40 °C to $+85$ °C C _L = 50 pF				
Item	Symbol	V _{cc} (V)*1	Min	Тур	Max	Min	Max	Unit
Maximum clock frequency	f _{max}	5.0	100	_	_	80	_	MHz
Propagation delay CP _n to Q ₇	t _{PLH}	5.0	1.0	10.0	12.5	1.0	13.5	ns
Propagation delay CP _n to Q ₇	t _{PHL}	5.0	1.0	9.5	12.0	1.0	13.0	_
Propagation delay MR to Q ₇	t _{PHL}	5.0	1.0	8.5	11.0	1.0	12.0	_

Note: 1. Voltage Range 5.0 is 5.0 V \pm 0.5 V

AC Operating Requirements: HD74ACT166

			Ta = +25°C C _L = 50 pF		$Ta = -40^{\circ}C$ to +85°C $C_{L} = 50 \text{ pF}$	_
Item	Symbol	V _{cc} (V)*1	Тур	Guaranteed	Minimum	Unit
Setup time \overline{PE} or P_n or D_s to CP_n	t _{su}	5.0	2.5	7.0	8.0	ns
Hold time CP _n to \overline{PE} or P _n or D _s	t _h	5.0	0.0	1.5	1.5	_
Pulse width CP _n or MR	t _w	5.0	4.5	7.0	8.0	
Recovery time $\overline{\text{MR}}$ to CP_n	t _{rec}	5.0	-2.5	0.5	0.5	

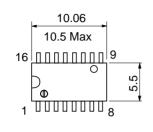
Note: 1. Voltage Range 5.0 is 5.0 V \pm 0.5 V

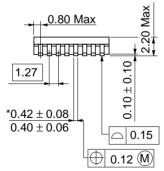
Capacitance

Item	Symbol	Тур	Unit	Condition
Input capacitance	C _{IN}	4.5	pF	V _{CC} = 5.5 V
Power dissipation capacitance	C_{PD}	35.0	pF	$V_{CC} = 5.0 \text{ V}$

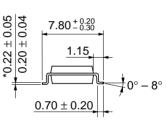
Unit: mm 19.20 20.00 Max 16 7.40 Max 6.30 1.3 1.11 Max 7.62 5.06 Max 2.54 Min 0.51 Min $0.25^{+0.13}_{-0.05}$ 0.48 ± 0.10 2.54 ± 0.25 $0^{\circ} - 15^{\circ}$ Hitachi Code DP-16 **JEDEC** Conforms EIAJ Conforms Weight (reference value) 1.07 g

Unit: mm





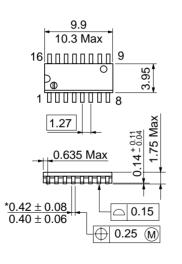


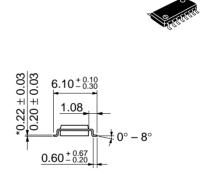


Hitachi Code	FP-16DA
JEDEC	
EIAJ	Conforms
Weight (reference value)	0.24 a

*Dimension including the plating thickness
Base material dimension

Unit: mm

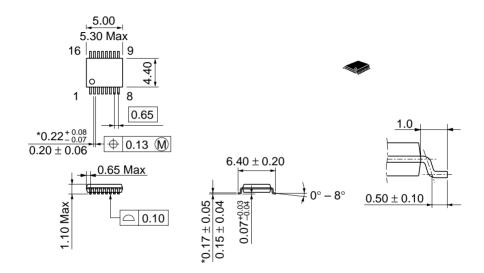




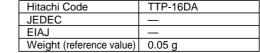
*Dimension including the plating thickness Base material dimension

Hitachi Code	FP-16DN
JEDEC	Conforms
EIAJ	Conforms
Weight (reference value)	0.15 g

Unit: mm



*Dimension including the plating thickness
Base material dimension



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